

Precision 300MHz to 7GHz RF Detector with Shutdown and Gain Adjustment

FEATURES

- Temperature Compensated Internal Schottky Diode RF Detector
- Wide Input Frequency Range: 300MHz to 7GHz*
- Wide Input Power Range: -32dBm to 10dBm
- Buffered Detector Output with External Gain Control
- Low Starting Voltage: 120mV $\pm$ 35mV for Gain = 2X
- Wide V_{CC} Range of 2.7V to 6V
- Low Operating Current: 500 μ A
- Low Shutdown Current: <2 μ A
- Available in a Low Profile (1mm) SOT-23 Package

APPLICATIONS

- 802.11a, 802.11b, 802.11g, 802.15, 802.16
- Multimode Mobile Phone Products
- Optical Data Links
- Wireless Data Modems
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

DESCRIPTION

The LTC[®]5530 is an RF power detector for RF applications operating in the 300MHz to 7GHz range. A temperature compensated Schottky diode peak detector and buffer amplifier are combined in a small ThinSOT[™] package. The supply voltage range is optimized for operation from a single lithium-ion cell or 3xNiMH.

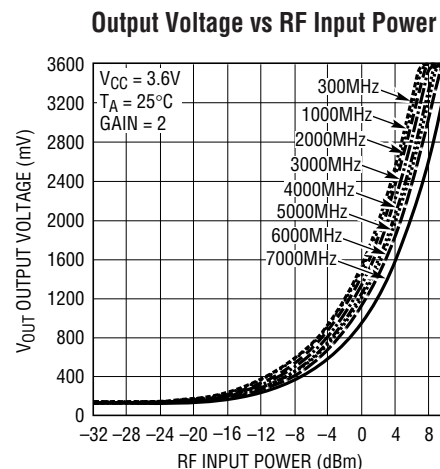
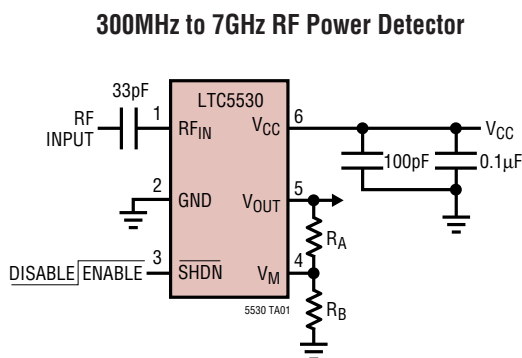
The RF input voltage is peak detected using an on-chip Schottky diode. The detected voltage is buffered and supplied to the V_{OUT} pin. The output buffer gain is set via external resistors. A power saving shutdown mode reduces current to less than 2 μ A.

The LTC5530 operates with input power levels from -32dBm to 10dBm.

LT, LTC and LT are registered trademarks of Linear Technology Corporation.
ThinSOT is a trademark of Linear Technology Corporation.

*Higher frequency operation is achievable with reduced performance. Consult factory for more information.

TYPICAL APPLICATION



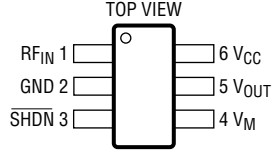
5530 TAO2

ABSOLUTE MAXIMUM RATINGS

(Note 1)

V_{CC} , V_{OUT} , $\overline{SHDN}$, V_M	–0.3V to 6.5V
RF_{IN} Voltage	($V_{CC} \pm 1.5V$) to 7V
RF_{IN} Power (RMS)	12dBm
I_{VOUT}	5mA
Operating Temperature Range (Note 2) ..	–40°C to 85°C
Maximum Junction Temperature	125°C
Storage Temperature Range	–65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

 S6 PACKAGE 6-LEAD PLASTIC TSOT-23 $T_{JMAX} = 125^{\circ}C$, $\theta_{JA} = 250^{\circ}C/W$	ORDER PART NUMBER
	LTC5530ES6
	S6 PART MARKING
	LBDX

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_{CC} = 3.6V$, $\overline{SHDN} = V_{CC} = HI$, $\overline{SHDN} = 0V = LO$, RF Input Signal is Off, $R_A = R_B = 1k$, $\overline{SHDN} = HI$ unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{CC} Operating Voltage	●	2.7		6	V
I_{VCC} Operating Current	$I_{VOUT} = 0mA$ ●		0.5	0.7	mA
I_{VCC} Shutdown Current	$\overline{SHDN} = LO$ ●		0.01	2	μA
V_{OUT} (No RF Input)	$R_{LOAD} = 2k$ ● $\overline{SHDN} = LO$	85	100 to 140 1	155	mV mV
V_{OUT} Output Current	$V_{OUT} = 1.75V$, $V_{CC} = 2.7V$, $\Delta V_{OUT} < 10mV$ ●	2	4		mA
V_{OUT} Enable Time	$\overline{SHDN} = LO$ to HI , $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ ●		8	20	μs
V_{OUT} Bandwidth	$C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ (Note 4)		2		MHz
V_{OUT} Load Capacitance	(Notes 6, 7) ●			33	pF
V_{OUT} Slew Rate	$V_{RFIN} = 1V$ Step, $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$ (Note 3)		3		V/ μs
V_{OUT} Noise	$V_{CC} = 3V$, Noise BW = 1.5MHz, 50 Ω RF Input Termination		1		mV _{P-P}
V_M Voltage Range	●	0		$V_{CC} - 1.8V$	V
V_M Input Current	●	–0.5		0.5	μA
$\overline{SHDN}$ Voltage LO, Chip Disabled	$V_{CC} = 2.7V$ to 6V ●			0.35	V
$\overline{SHDN}$ Voltage HI, Chip Enabled	$V_{CC} = 2.7V$ to 6V ●	1.4			V
$\overline{SHDN}$ Input Current	$\overline{SHDN} = 3.6V$ ●		22	36	μA
RF_{IN} Input Frequency Range	(Note 8)		300 to 7000		MHz
RF_{IN} Input Power Range	RF Frequency = 300MHz to 7GHz (Note 5, 6) $V_{CC} = 2.7V$ to 6V		–32 to 10		dBm
RF_{IN} AC Input Resistance	$F = 1000MHz$, $P_{in} = -25dBm$		220		Ω
RF_{IN} Input Shunt Capacitance	$F = 1000MHz$, $P_{in} = -25dBm$		0.65		pF

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: The rise time at V_{OUT} is measured between 1.3V and 2.3V.

Note 4: Bandwidth is calculated based on the 10% to 90% rise time

equation: $BW = 0.35/\text{rise time}$.

Note 5: RF performance is tested at 1800MHz

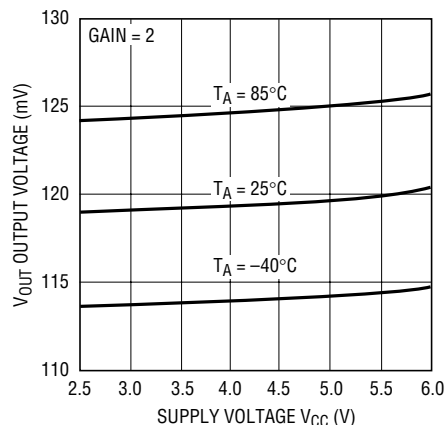
Note 6: Guaranteed by design.

Note 7: Capacitive loading greater than this value may result in circuit instability.

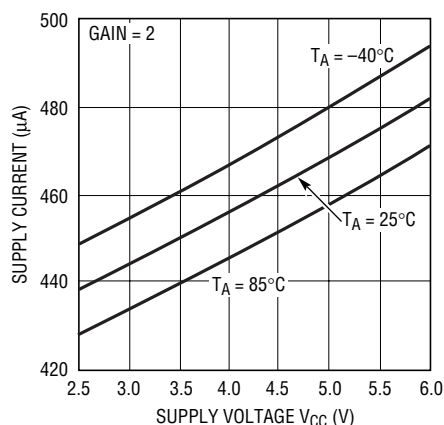
Note 8: Higher frequency operation is achievable with reduced performance. Consult factory for more information.

TYPICAL PERFORMANCE CHARACTERISTICS

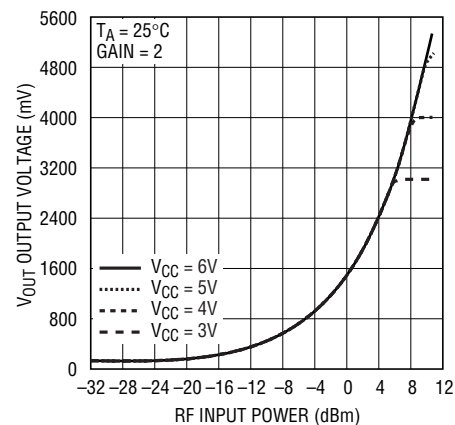
Output Voltage vs Supply Voltage
(RF Input Signal Off)



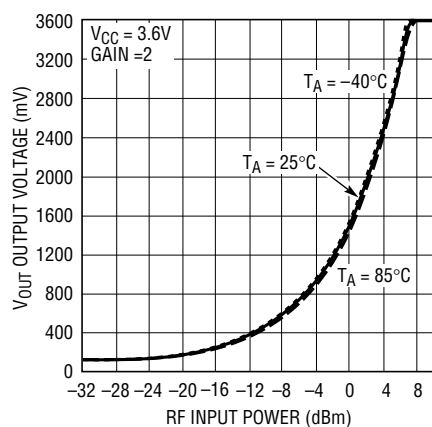
Supply Current vs Supply Voltage
(RF Input Signal Off)



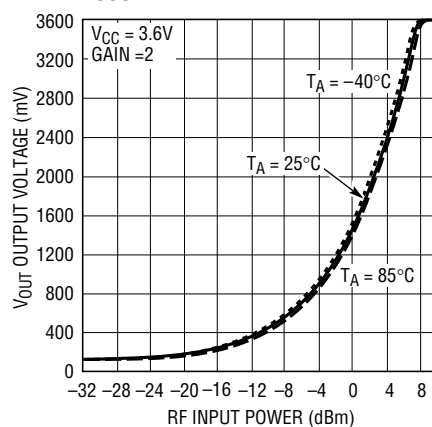
V_{OUT} vs RF Input Power and V_{CC}
1000MHz



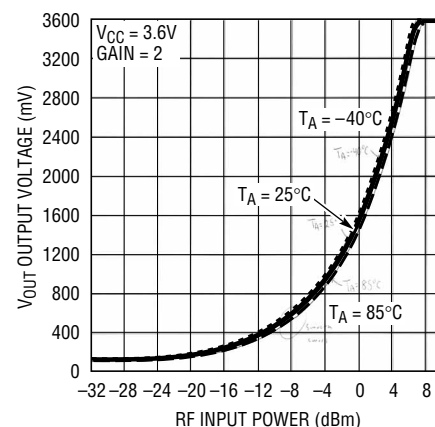
Typical Detector Characteristics,
300MHz



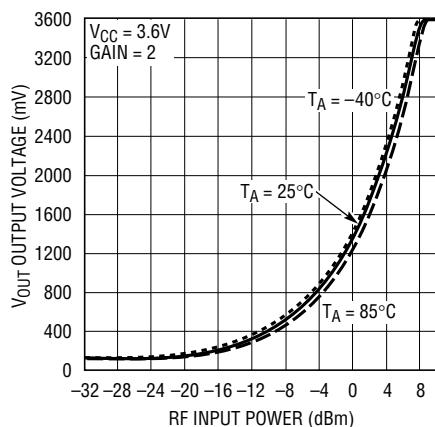
Typical Detector Characteristics,
1000MHz



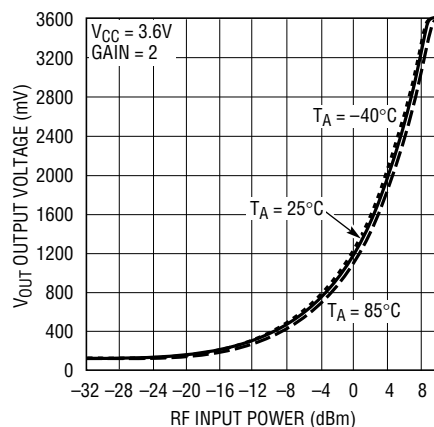
Typical Detector Characteristics,
2000MHz



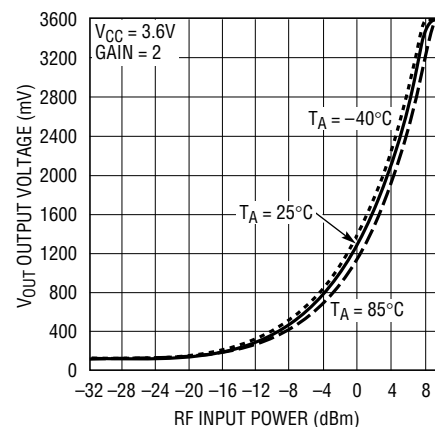
Typical Detector Characteristics,
3000MHz



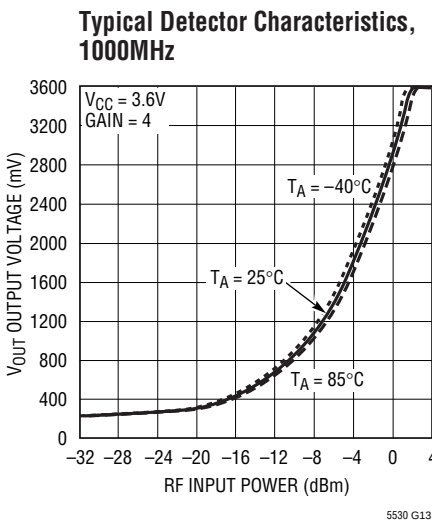
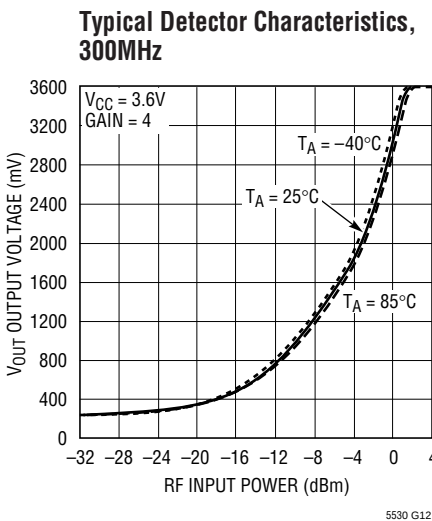
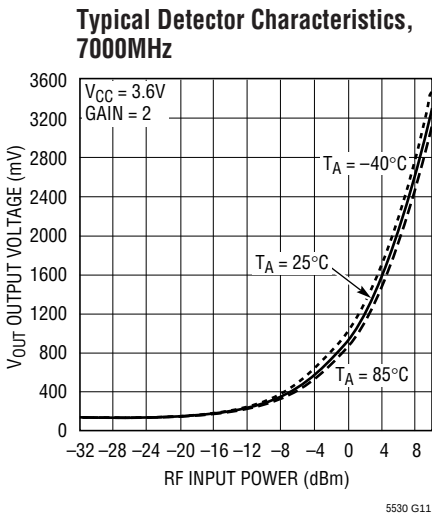
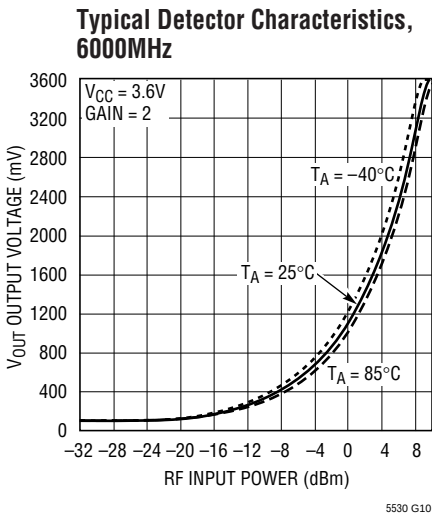
Typical Detector Characteristics,
4000MHz



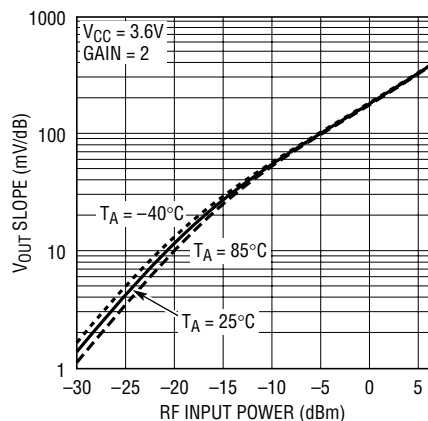
Typical Detector Characteristics,
5000MHz



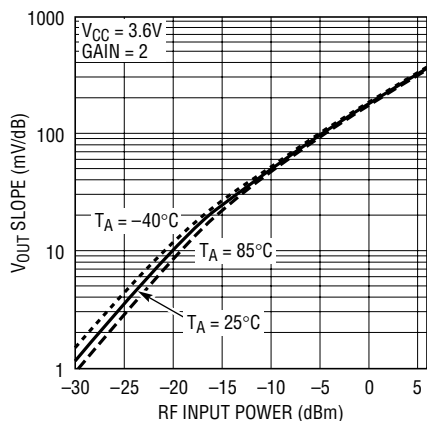
TYPICAL PERFORMANCE CHARACTERISTICS



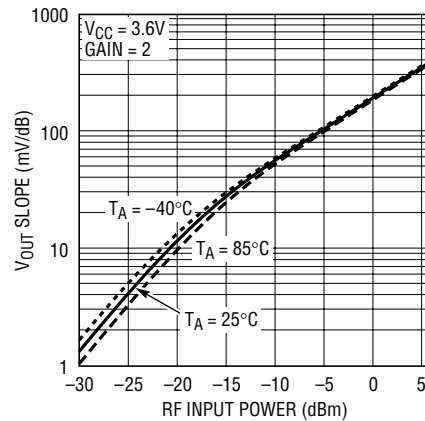
TYPICAL PERFORMANCE CHARACTERISTICS

**V_{OUT} Slope vs RF Input Power
300MHz**

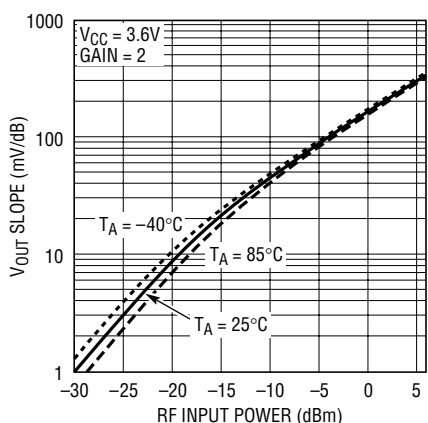
5530 G14

**V_{OUT} Slope vs RF Input Power
1000MHz**

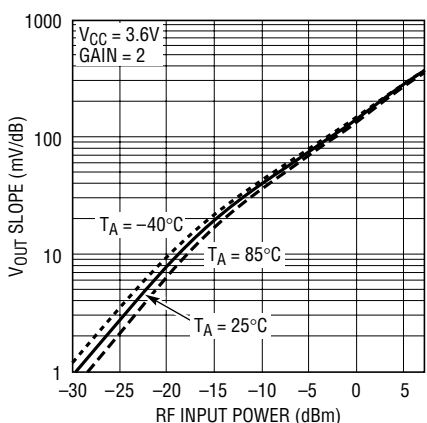
5530 G15

**V_{OUT} Slope vs RF Input Power
2000MHz**

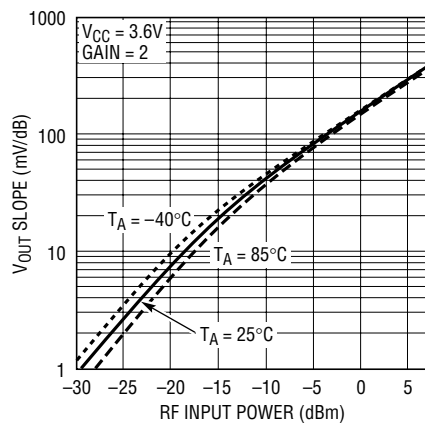
5530 G16

**V_{OUT} Slope vs RF Input Power
3000MHz**

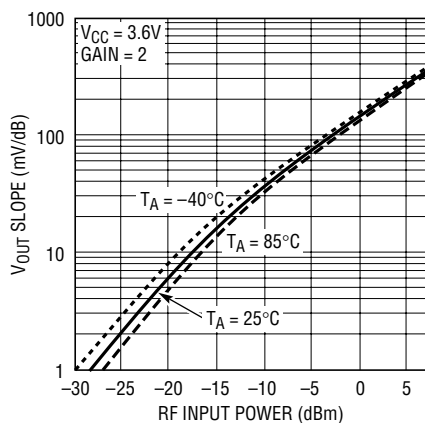
5530 G17

**V_{OUT} Slope vs RF Input Power
4000MHz**

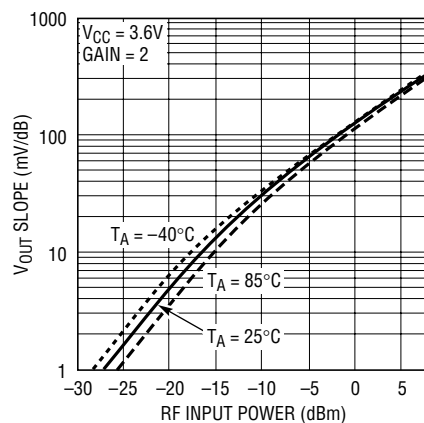
5530 G18

**V_{OUT} Slope vs RF Input Power
5000MHz**

5530 G19

**V_{OUT} Slope vs RF Input Power
6000MHz**

5530 G20

**V_{OUT} Slope vs RF Input Power
7000MHz**

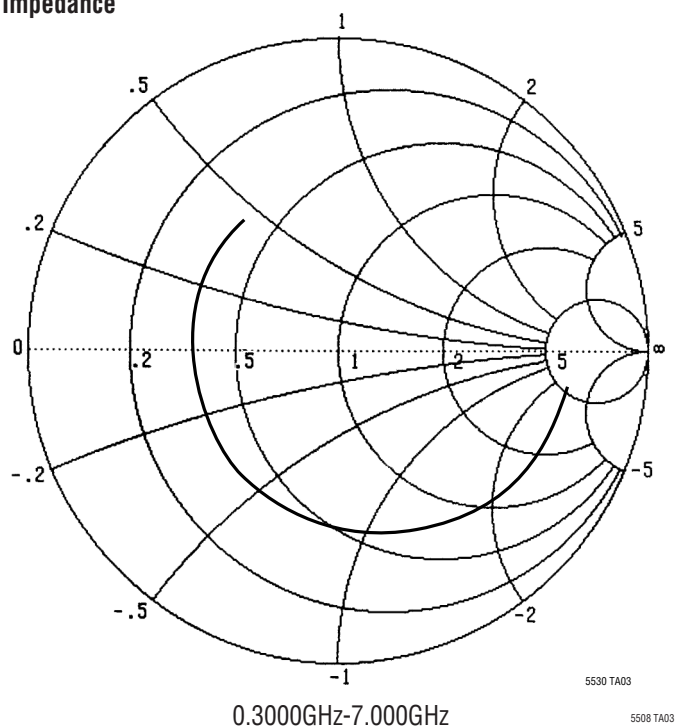
5530 G21

TYPICAL PERFORMANCE CHARACTERISTICS

RF_{IN} Input Impedance (Pin = 0dBm, V_{CC} = 3.6V, T_A = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
0.30	290.45	-136.22
0.50	234.41	-162.54
0.70	178.25	-170.53
0.90	137.31	-159.89
1.10	109.17	-147.57
1.30	86.30	-136.18
1.50	68.65	-121.74
1.70	57.48	-107.60
1.90	49.79	-96.72
2.10	43.56	-86.70
2.30	38.67	-77.91
2.50	34.82	-70.13
2.70	31.68	-62.86
2.90	29.13	-56.01
3.10	27.17	-49.83
3.30	25.73	-44.24
3.50	24.56	-39.74
3.70	23.18	-35.35
3.90	22.31	-30.62
4.10	20.73	-26.88
4.30	19.88	-22.31
4.50	19.40	-18.23
4.70	19.05	-14.25
4.90	19.08	-10.21
5.10	19.55	-6.30
5.30	20.85	-2.84
5.50	21.94	-1.49
5.70	20.60	-0.07
5.90	19.29	2.99
6.10	18.69	6.61
6.30	18.53	10.39
6.50	18.74	14.35
6.70	19.79	17.91
6.90	19.75	20.77
7.00	19.99	22.47

S11 Forward Reflection
Impedance



S11 Forward Reflection Impedance

A Smith Chart for the 5530 TA04 tube. The chart is a circular plot with a horizontal real axis and a vertical imaginary axis. The real axis is labeled with values 0, .2, .5, 1, 2, 5, and ∞ on the right side, and -0.2, -0.5, -1, -2, -5 on the left side. The imaginary axis is labeled with values 1, 2, 5, and ∞ on the top, and -1, -2, -5 on the bottom. The chart is divided into concentric circles and radial lines. The text "5530 TA04" is printed in the bottom right corner of the chart area.

PIN FUNCTIONS

RF_{IN} (Pin 1): RF Input Voltage. Referenced to V_{CC} . A coupling capacitor must be used to connect to the RF signal source. The frequency range is 300MHz to 7GHz. This pin has an internal 500Ω termination, an internal Schottky diode detector and a peak detector capacitor.

GND (Pin 2): Ground.

$\overline{\text{SHDN}}$ (Pin 3): Shutdown Input. A logic low on the $\overline{\text{SHDN}}$ pin places the part in shutdown mode. A logic high enables the part. $\overline{\text{SHDN}}$ has an internal $160k$ pulldown resistor to

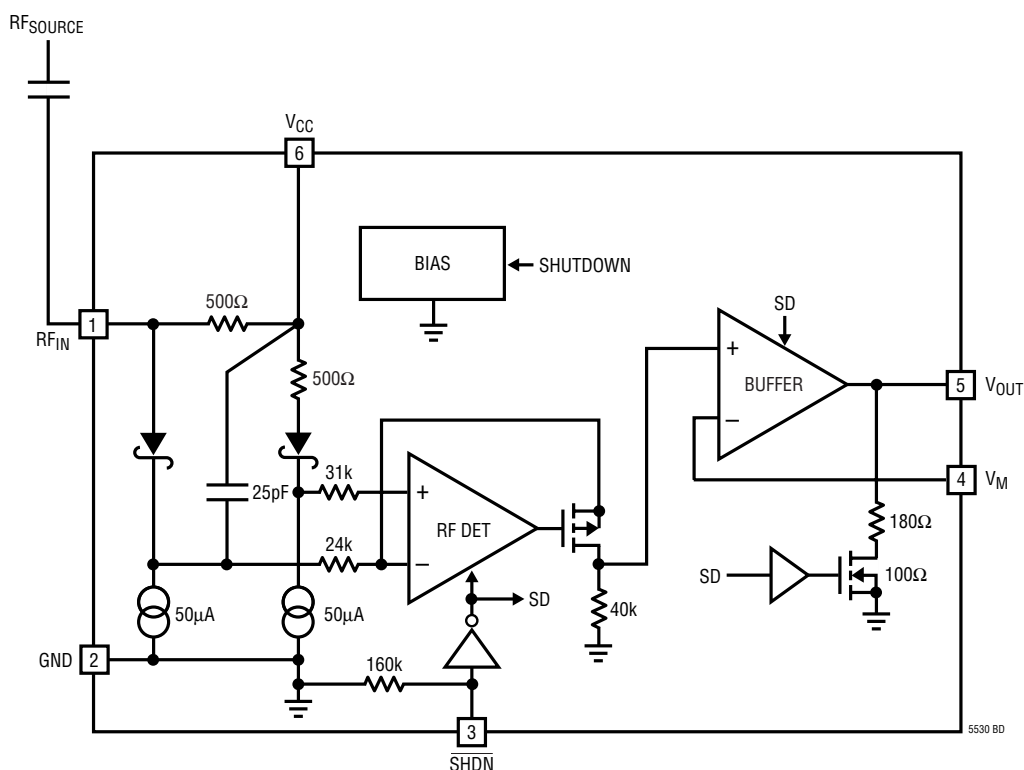
ensure that the part is in shutdown when no input is applied. In shutdown V_{OUT} is connected to ground via a 280Ω resistor.

V_M (Pin 4): Negative Input to Buffer Amplifier.

V_{OUT} (Pin 5): Detector Output.

V_{CC} (Pin 6): Power Supply Voltage, 2.7V to 6V. V_{CC} should be bypassed appropriately with ceramic capacitors.

BLOCK DIAGRAM



APPLICATIONS INFORMATION

Operation

The LTC5530 RF detector integrates several functions to provide RF power detection over frequencies ranging from 300MHz to 7GHz. These functions include an internal frequency compensated buffer amplifier, an RF Schottky diode peak detector and level shift amplifier to convert the RF input signal to DC and a delay circuit to avoid voltage transients at V_{OUT} when powering up. The LTC5530 has both shutdown and gain setting capabilities.

Buffer Amplifier

The output buffer amplifier is capable of supplying typically 4mA into a load. The negative terminal V_M is brought out to a pin for gain selection. External resistors connected between V_{OUT} and V_M (R_A) and V_M to ground (R_B) will set the amplifier gain.

$$GAIN = 1 + \frac{R_A}{R_B}$$

The amplifier is unity gain stable; however a minimum gain of two is recommended to improve low output voltage accuracy. The amplifier bandwidth is 2MHz for a gain of 2.

For increased gain applications, the bandwidth is reduced according to the formula:

$$BANDWIDTH = \frac{4MHz}{(GAIN)} = 4MHz \cdot \frac{R_B}{(R_A + R_B)}$$

A capacitor can be placed across the feedback resistor R_A to shape the frequency response. In addition the amplifier can be used as a comparator. V_M can be connected to a reference voltage. When the internal detector voltage (which is connected to the positive input of the buffer amplifier) exceeds the external voltage of V_M , V_{OUT} will switch high.

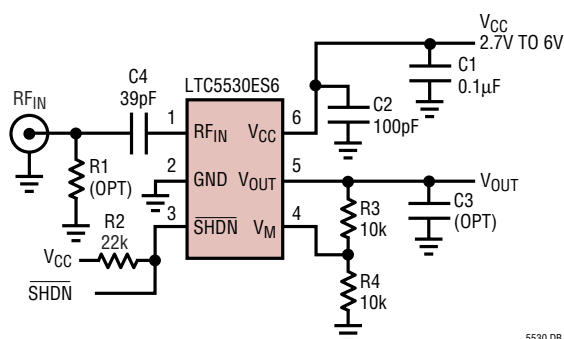
RF Detector

The internal RF Schottky diode peak detector and level shift amplifier converts the RF input signal to a low frequency signal. The detector demonstrates excellent efficiency and linearity over a wide range of input power. The Schottky diode is biased at about 55µA and drives a 25pF internal peak detector capacitor.

Shutdown

The part is in shutdown mode when $\overline{SHDN}$ is low. The supply current is reduced to < 2µA and V_{OUT} is shorted to ground via a 280Ω resistor. When $\overline{SHDN}$ is asserted high, the part is enabled after about 8µs.

Demo Board Schematic



5530 DB

APPLICATIONS INFORMATION

Applications

The LTC5530 can be used as a self-standing signal strength measuring receiver for a wide range of input signals from -32dBm to 10dBm for frequencies from 300MHz to 7GHz .

Operation at higher frequencies is achievable. Consult factory for more information.

The LTC5530 can be used as a demodulator for AM and ASK modulated signals with data rates up to 2MHz . Depending on specific application needs, the RSSI output can be split between two branches, providing AC-coupled

data (or audio) output and DC-coupled RSSI output for signal strength measurements and AGC.

The LTC5530 can be used for RF power detection and control. Figure 1 is an example of transmitter power control, using the LTC5530 with a capacitive tap to the power amplifier. A 0.5pF capacitor ($C1$) followed by a 200Ω resistor ($R1$) forms a coupling circuit with about 20dB loss at 900MHz referenced to the LTC5530 RF input pin. In the actual product implementation, component values for the capacitive tap may be different depending on parts placement, PCB parasitics and parameters of the antenna.

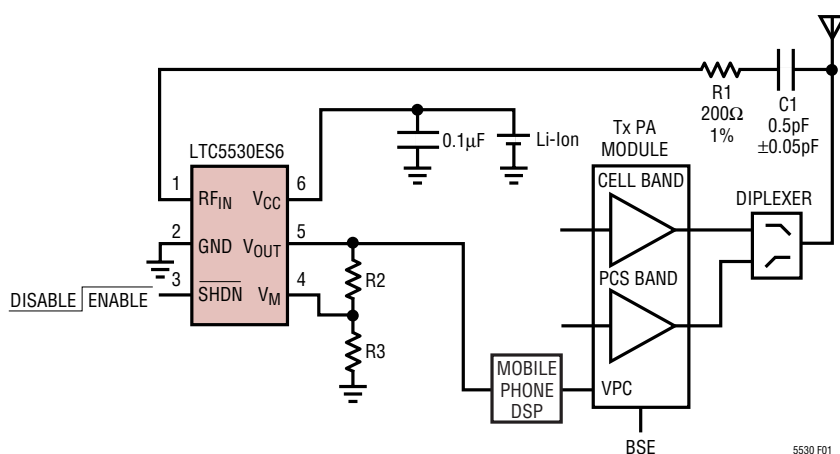
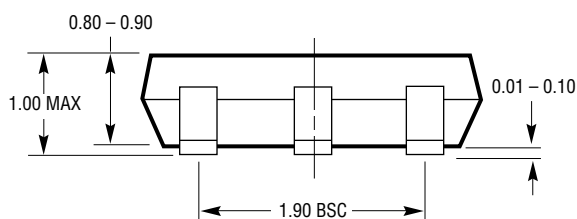
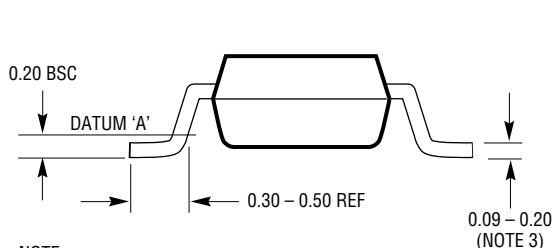
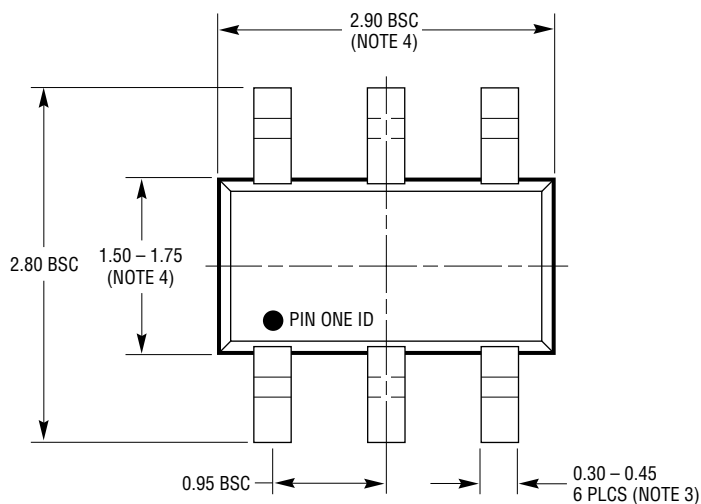
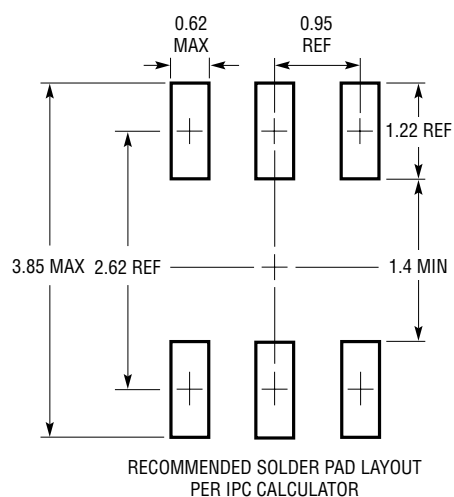


Figure 1. Mobile Phone Tx Power Control Application with a Capacitive Tap

5530 F01

PACKAGE DESCRIPTION

S6 Package
6-Lead Plastic TSOT-23
 (Reference LTC DWG # 05-08-1636)



- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
 2. DRAWING NOT TO SCALE
 3. DIMENSIONS ARE INCLUSIVE OF PLATING
 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
 6. JEDEC PACKAGE REFERENCE IS MO-193

S6 TSOT-23 0302

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
Infrastructure		
LT5511	High Linearity Upconverting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	DC-3GHz High Signal Level Downconverting Mixer	DC to 3GHz, 21dBm IIP3, Integrated LO Buffer
LT5515	1.5GHz to 2.5GHz Direct Conversion Quadrature Demodulator	20dBm IIP3, Integrated LO Quadrature Generator
LT5516	0.8GHz to 1.5GHz Direct Conversion Quadrature Demodulator	21.5dBm IIP3, Integrated LO Quadrature Generator
LT5517	40MHz to 900MHz Direct Conversion Quadrature Demodulator	21dBm IIP3, Integrated LO Quadrature Generator
LT5519	0.7GHz to 1.4GHz High Linearity Upconverting Mixer	17.1dBm IIP3, 50 Ω Single Ended RF and LO Ports
LT5520	1.3GHz to 2.3GHz High Linearity Upconverting Mixer	15.9dBm IIP3, 50 Ω Single Ended RF and LO Ports
LT5522	600MHz to 2.7GHz High Linearity Downconverting Mixer	4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz, NF = 12.5dB, 50 Ω Single-Ended RF and LO Ports
RF Power Detectors		
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.25V Supply
LTC®5505	300MHz to 3GHz RF Power Detectors	LTC5505-1: -28dBm to 18dBm Range, LTC5505-2: -32dBm to 12dBm Range, Temperature Compensated, 2.7V to 6V Supply
LTC5507	100kHz to 1000MHz RF Power Detector	-34dBm to 14dBm Range, Temperature Compensated, 2.7V to 6V Supply
LTC5508	300MHz to 7GHz RF Power Detector	-32dBm to 12dBm Range, Temperature Compensated, SC70 Package
LTC5509	300MHz to 3GHz RF Power Detector	36dB Dynamic Range, Temperature Compensated, SC70 Package
LTC5531	300MHz to 7GHz Precision RF Power Detector	Precision V_{OUT} Offset Control and Shutdown
LTC5532	300MHz to 7GHz Precision RF Power Detector	Precision V_{OUT} Offset Control, Adjustable Gain and Offset
RF Building Blocks		
LT5500	1.8GHz to 2.7GHz Receiver Front End	1.8V to 5.25V Supply, Dual-Gain LNA, Mixer, LO Buffer
LT5502	400MHz Quadrature IF Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Upconverting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, -4dB to 57dB Linear Power Gain, 8.8MHz Baseband Bandwidth
LT5546	500MHz Quadrature IF Demodulator with VGA and 17MHz Baseband Bandwidth	17MHz Baseband Bandwidth, 40MHz to 500MHz IF, 1.8V to 5.25V Supply, -7dB to 56dB Linear Power Gain
RF Power Controllers		
LTC1757A	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC1758	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC1957	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC4400	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW
LTC4401	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW
LTC4403	RF Power Controller for EDGE/TDMA	Multiband GSM/GPRS/EDGE Mobile Phones, 250kHz Loop BW